

Data sheet acquired from Harris Semiconductor SCHS076D – Revised March 2004

CMOS Dual Up-Counters

High-Voltage Types (20-Volt Rating)

CD4518B Dual BCD Up-Counter CD4520B Dual Binary Up-Counter

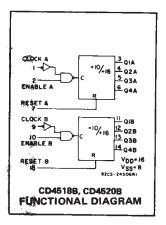
CD4518 Dual BCD Up-Counter and CD4520 Dual Binary Up-Counter each consist of two identical, internally synchronous 4-stage counters. The counter stages are D-type flip-flops having interchangeable CLOCK and ENABLE lines for incrementing on either the positive-going or negative-going transition. For single-unit operation the ENABLE input is maintained high and the counter advances on each positive-going transition of the CLOCK. The counters are cleared by high levels on their RESET lines.

The counter can be cascaded in the ripple mode by connecting Q4 to the enable input of the subsequent counter while the CLOCK input of the latter is held low.

The CD4518B and CD4520B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- Medium-speed operation —
 6-MHz typical clock frequency at 10 V₂
- Positive- or negative-edge triggering
- Synchronous internal carry propagation
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range;
 100 nA at 18 V and 25°C
- Noise margin(over full package-temperature range): 1 V at V_{DD} = 5 V
 2 V at V_{DD} = 10 V
 - 2.5 V at $V_{DD} = 15 \text{ V}$
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output
 Characteristics
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



Applications:

- Multistage synchronous counting
- Multistage ripple counting
- Frequency dividers

TRUTH TABLE

CLOCK	ENABLE	RESET	ACTION
_	1	0	Increment Counter
0	~	0	Increment Counter
7	х	0	No Change
Х		0	No Change
_	0	0	No Change
1		0	No Change
Х	х	1	Q1 thru Q4 = 0

X = Don't Care	1 = High State	0 = Low State

MAXIMUM RATINGS, Absolute-Maximum Values: DC SUPPLY-VOLTAGE RANGE, (VDD)

Voltages referenced to V _{SS} Terminal)0.5V to +20V
IPUT VOLTAGE RANGE, ALL INPUTS
C INPUT CURRENT, ANY ONE INPUT
OWER DISSIPATION PER PACKAGE (PD):
For T _A = -55°C to +100°C
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
EVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
PERATING-TEMPERATURE RANGE (T _A)
TORAGE TEMPERATURE RANGE (T _{stg})65°C to +150°C
FAD TEMPERATURE (DURING SOI DERING):

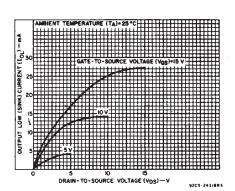


Fig. 1 — Typical output low (sink) current characteristics.

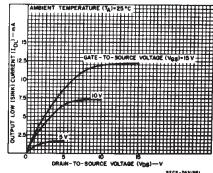
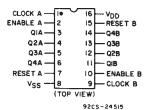


Fig. 2 — Minimum output low (sink) current characteristics.



CD4518B, CD4520B TERMINAL ASSIGNMENT

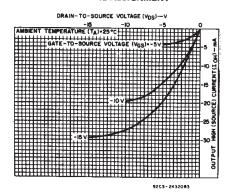


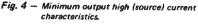
Fig. 3 — Typical output high (source) current characteristics.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	HOITION	IS	LIMI	TS AT I	NDICAT	ED TEI	MPERA	TURES	(°C)	UNITS
ISTIC	Vo	VIN	VDD						+25		014113
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device		0,5	5	5	5	150	150		0.04	5	
Current,		0,10	10	10	10	300	300	-	0.04	10	μÁ
IDD Max.		0,15	15	20	20	600	600	_	0.04	20	μ^
	-	0,20	20	100	100	3000	3000	-	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0,5	0,10	10	1.6	1.5	1.1	.0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	-	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-]
Current, IOH Min.	9.5	0,10	10	-1.6	-1.5	-1.1	0.9	-1.3	-2.6	-	
10H WIII.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:	_	0,5	5		0	.05		_	0	0.05	
Low-Level, VOL Max.	_	0,10	10		0	.05			0	0.05	
* ULax.	_	0,15	15		0	.05			. 0	0.05	v
Output Voltage:	<u>`</u> -	0,5	5		4	.95		4.95	5	_	ľ
High-Level,		0,10	∽10		9	.95	•	9.95	10	_	*
VOH Min.	-	0,15	15		14	1.95		14.95	15	-	
Input Low	0.5, 4.5	-	5		1	.5		_	_	1.5	
Voltage,	1, 9	_	10			3		_	_	3	
VIL Max.	1.5,13.5	_	15			4		-	_	4	v
Input High	0.5, 4.5	_	5		3	3.5		3.5	_		v
Voltage,	1, 9		10			7 .		7			
VIH Min.	1.5,13.5	-	15		-	11		11	-	_	
Input Current IJN Max.	_	0,18	18	±0.1	±0.1	±1	±1	- ()	±10 ⁻⁵	±0.1	μΑ



DRAIN-TO-SOURCE VOLTAGE (VDS)



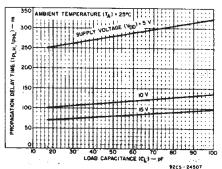


Fig. 5 - Typical propagation delay vs. load capacitance, clock or enable to output.

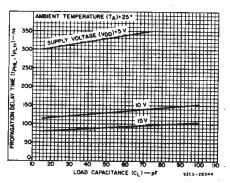


Fig. 6 — Typical propagation delay time vs. load capacitance, reset to output.

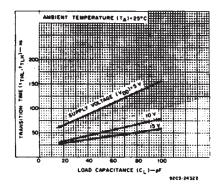
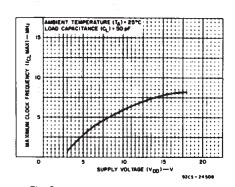


Fig. 7 - Typical transition time vs. load capacitance.



CD4518B, CD4520B Types

Fig. 8 — Typical maximum-clock-frequency vs. supply voltage.

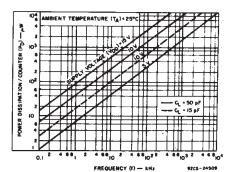


Fig. 9 - Typical power dissipation characteristics.

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}C$, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD}	LII	MITS	UNITS
	(V)	Min.	Max.	1
Supply Voltage Range (For TA=Full Package- Temperature Range)		3	18	V
	5	400	· -	
Enable Pulse Width, tW	10	200	- .	ns
	15	140		
	5	200	- `	
Clock Pulse Width, tw	10	100		ns
	15	. 70	. =	
	5		1.5	
Clock Input Frequency, fCL	10	dc	3	MHz
	15		. 4	1
Clock Rise or Fall Time, t _r CL or t _f CL:	5 10 15		15 5 5	μs
	5	250	-	
Reset Pulse Width, tw	10	. 110		ns
**	15	80		

DYNAMIC ELECTRICAL CHARACTERISTICS at TA=25°C; Input tr,tq=20 ns, CL=50 pF, RL=200 K Ω

CHARACTERISTIC	TEST CON	DITIONS	ı	IMIT	S	UNITS
		V _{DD}	Min.	Typ.	Max.	
Propagation Delay Time, tpHL, tpLH: Clock or Enable to Output		5 10 15	- -	280 115 80	560 230 160	
Reset to Output		5 10 15	-	330 130 90	650 225 170	ns
Transition Time, t _{THL} , t _{TLH}		5 10 15		100 50 40	200 100 80	ns
Maximum Clock Input Frequency, fCL		5 10 15	1.5 3 4	3 6 8	-	MHz
Minimum Clock Pulse Width, t _W		5 10 15		100 50 35	200 100 70	ns
Clock Rise or Fall Time, t _r or t _f :		5 10, 15	1	.1 4	15 5	μς
Minimum Reset Pulse Width, tw		5 10 15	-	125 55 40	250 110 80	ns
Minimum Enable Pulse Width, tw	7	5 10 15	-	200 100 70	400 200 140	ns
Input Capacitance, C _{IN}	Any Input			5	7.5	ρF

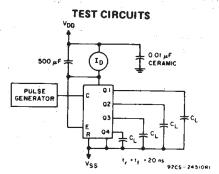


Fig. 10 — Dynamic power dissipation.

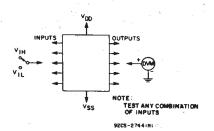


Fig. 11 - Input voltage.

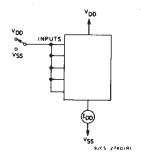


Fig. 12 — Quiescent device current test circuit.

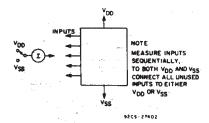
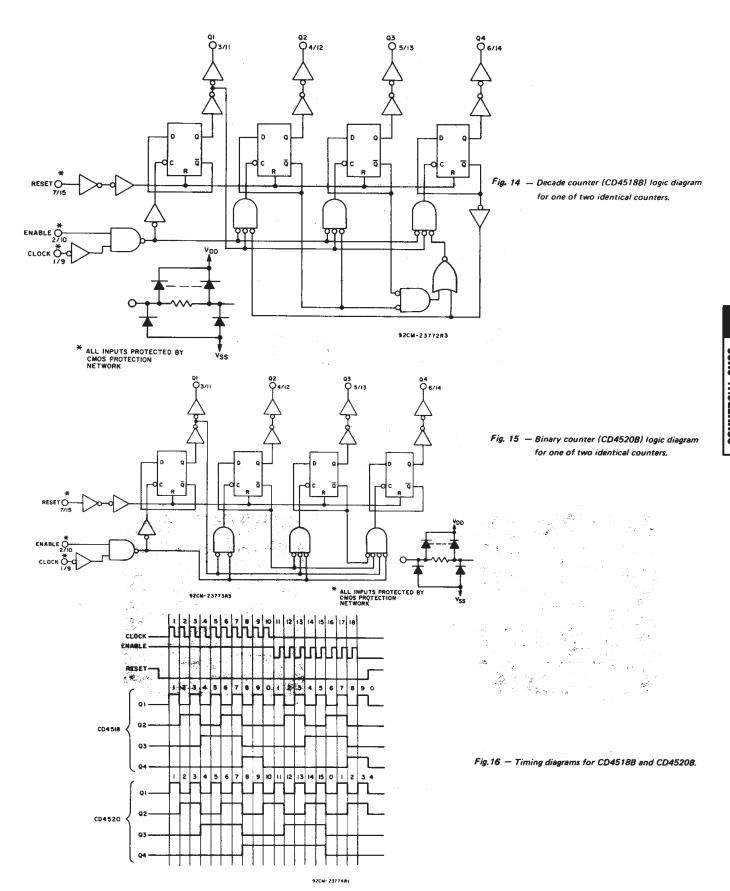


Fig. 13 — Input leakage-current test oircuit.



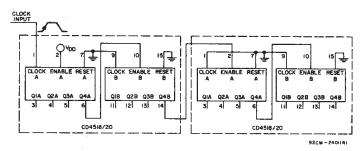
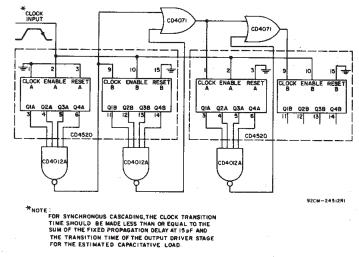
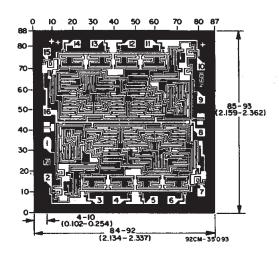


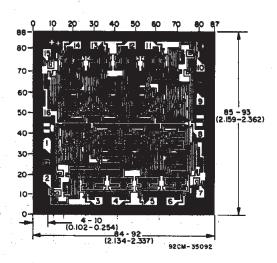
Fig. 17 - Ripple cascading of four counters with positive edge triggering.



 ${\it Fig. 18-Synchronous\ cascading\ of\ four\ binary\ counters\ with\ negative\ edge\ triggering.}$



Dimensions and pad layout for CD45188H chip.



Dimensions and pad layout for CD4520BH chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils $(10^{-3} \, \text{inch})$.



www.ti.com 15-Oct-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
7702301EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4518BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4518BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4518BF	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4518BF3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4518BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4518BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4520BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4520BF	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4520BF3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type
CD4520BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

www.ti.com 15-Oct-2009

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4520BM96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4520BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

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to Customer on an annual basis.



2008 19-Mar-2008

TAPE AND REEL INFORMATION

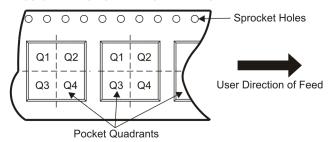




_		
		Dimension designed to accommodate the component width
ſ	B0	Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
Γ	P1	Pitch between successive cavity centers

- Reel Width (W1)

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4518BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4518BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4518BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
CD4520BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4520BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4520BPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4518BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4518BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4518BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
CD4520BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4520BNSR	SO	NS	16	2000	346.0	346.0	33.0
CD4520BPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

D (R-PDS0-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



D(R-PDSO-G16)



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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